
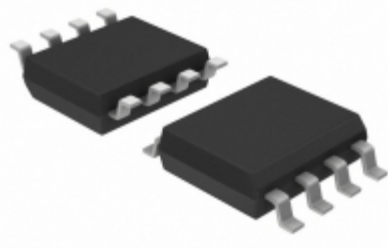
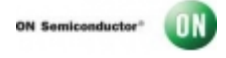
	<h2 style="color: red;">NVMD3P03R2G</h2>
	<p>Hersteller-Teilenummer: NVMD3P03R2G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET 2P-CH 30V 2.34A 8SOIC</p> <hr/> <p>Datenblätter:  NVMD3P03R2G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 2433 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMD3P03R2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2P-CH 30V 2.34A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2433 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	730mW
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.34A
Rds On (Max) @ Id, Vgs	85 mOhm @ 3.05A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 24V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NVMD6N04R2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 4.6A 8-SOIC</p>	 <p>NVM100026 TDK-Lambda Americas, Inc. AC/DC CONVERTER 24V 180W</p>	 <p>NVMD6N03R2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 6A 8SOIC</p>	 <p>NVMD6N04 AMI Semiconductor / ON Semiconductor NVMD6N04 ON</p>
 <p>NVMD6P02R2G AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 4.8A 8-SOIC</p>	 <p>NVM100015 TDK-Lambda Americas, Inc. AC/DC CONVERTER 12V 180W</p>	 <p>NVMD4N03R2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 4A SO8FL</p>	 <p>NVMD3P03 AMI Semiconductor / ON Semiconductor NVMD3P03 ON</p>

heiße Teile

Mehr

 06031U101GAT2A	 12065C562KAT4A	 AAT3238IJS-2.8-T1	 ACMD-7401TR1G	 AD9051BRSZ
 ADE7858ACPZ-RL	 ASFLMB-25.000MHZ-LC-T	 BD7903FS-E2	 BSM35GB120DLC	 CBPC3508W
 CTX1-4P-R	 D66EV550	 DMN4800LSS-13-F	 DS36954MX/NOPB	 EM6353BZ2SP3B-4.6
 GRM0225C1E7R3BDAEL	 GRM1885C1H271GA01J	 GRM1886P1H5R4DZ01D	 ID9301-25A30R	 KA75310MTF
 KK40F.80	 LH1056AT	 LM1084S-3.3	 MAX549AUA+	 MAX6163AESA
 MC88915TFN70R2	 NCP500SN27T1G	 NJL21H380F3	 NJM2903V	 NVMD3P03
 NVMD4N03	 NVMD6N04	 NVMFD5853NLT1G	 NVMFD5877NLT3G	 NVMFD5877NLWFT1G
 NVMFS4C01NWFT1G	 NVMFS4C05N	 NVMFS5113PLT1G	 NVMFS5830NLWFT1G	 NVMFS5885NLT3G
 NVMFS5C450NT1G	 NVMFS5C456NLT1G	 NVMFS5C468NLT1G	 OP295GSZ-REEL	 RR1220R-564-B-T5
 SC79212DR2	 SI4431CDY-T1-GE3	 SN7534051N	 ST1000C28K1	 VS-30EPH06PBF

Contact us: Info@Y-IC.com

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